NSN 5961-00-275-7332

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-275-7332 **Inclosure Material:** Metal **Overall Length:** 1.276 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 3.20 amperes forward current, total rms nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 50.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpnp **Terminal Type And Quantity:** 2 unthreaded hole and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0